
 $^{114}\text{Sn}(\text{p},\text{d})$ IAS 1980Ta04

Type	Author	History		Literature Cutoff Date
		Citation		
Full Evaluation	Jean Blachot	NDS 111, 1471 (2010)		1-May-2009

E=55 MeV. Measured ED, $\theta=11^\circ$ and 23° , magnetic spectrograph, 1980Ta04.

 ^{113}Sn Levels

E(level)	J^π [†]	S [‡]	Comments
11826 50	(9/2 ⁺)	0	$\Gamma=22$ keV 10 E(level): IAS of ^{113}In g.s.
12254 50	(1/2 ⁻)	428 5	$\Gamma=20$ keV 8 E(level): IAS of $^{113}\text{In}(392)$.
12513 50	(3/2 ⁻)	687 5	$\Gamma=25$ keV 9 E(level): IAS of $^{113}\text{In}(647)$.

[†] From J^π of parent state.

[‡] E(level)-E(g.s. analog).